## NSN 5961-00-139-2613

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**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-139-2613 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.340 inches **Overall Diameter:** 0.500 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 60.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 1.00 amperes source cutoff current and 3.00 amperes collector current, dc **Power Rating Per Characteristic:** 35.0 watts collector power dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Precious Material And Location:** Terminals surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization: No